

### **Features**

- Low R<sub>DS(ON)</sub>
- Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

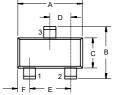
# **P-Channel MOSFET**

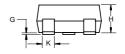
# **Maximum Ratings**

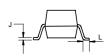
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 90°C/W Junction to Ambient(Note 1)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	$V_{GS}$	±10	V
Drain Current-Continuous	I <sub>D</sub>	-4.2	Α
Drain Current-Pulse <sup>(Note 2)</sup>	I <sub>DM</sub>	-21	Α
Power Dissipation	P <sub>D</sub>	1.4	W

# SOT-23

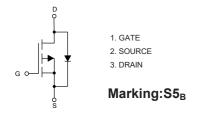




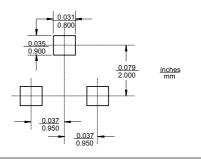


		DIMENSIONS					
	DIM	INCHES		MM		NOTE	
	DIIVI	MIN	MAX	MIN	MAX	NOTE	
	Α	0.110	0.120	2.80	3.04		
	В	0.083	0.104	2.10	2.64		
	С	0.047	0.055	1.20	1.40		
	D	0.034	0.041	0.85	1.05		
	Е	0.067	0.083	1.70	2.10		
	F	0.018	0.024	0.45	0.60		
	G	0.0004	0.006	0.01	0.15		
	Н	0.035	0.043	0.90	1.10		
	J	0.003	0.007	0.08	0.18		
	K	0.012	0.020	0.30	0.51		
	Ĺ	0.007	0.020	0.20	0.50		

# Internal Structure



#### Suggested Solder Pad Layout





## ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

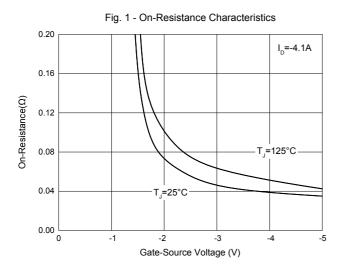
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-20			V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-0.5		-0.9	V	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V			-1	μA	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.7A		35	60	mΩ	
Drain-Source On-Resistance <sup>(Note 3)</sup>		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.7A		46	80		
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-2.7A		90			
Forward Tranconductance <sup>(Note 3)</sup>	<b>9</b> FS	$V_{DS}$ =-5V, $I_{D}$ =-4.1A	6			S	
<b>Dynamic Characteristics</b>							
Input Capacitance(Note 1,4)	C <sub>iss</sub>			740			
Output Capacitance <sup>(Note 1,4)</sup>	C <sub>oss</sub>	$V_{DS}$ =-4V, $V_{GS}$ =0V, f=1MHz		290		pF	
Reverse Transfer Capacitance (Note 1,4)	C <sub>rss</sub>			190			
Total Gate Charge <sup>(Note 1)</sup>	$Q_g$	V <sub>DS</sub> =-4V,V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-4.1A		7.8	15		
Total Gate Charge	<b>Q</b> g			4.5	9	nC	
Gate-Source Chage <sup>(Note 1)</sup>	$Q_{gs}$	$V_{DS}$ =-4V, $V_{GS}$ =-2.5V, $I_{D}$ =-4.1A		1.2			
Gage-Drain Charge <sup>(Note 1)</sup>	$Q_{gd}$			1.6			
Gate Resistance <sup>(Note 1,4)</sup>	R <sub>g</sub>	f=1MHz	1.4	7	14	Ω	
Turn-On Delay Time <sup>(Note 1,4)</sup>	t <sub>d(on)</sub>			13	20		
Turn-On Rise Time <sup>(Note 1,4)</sup>	t <sub>r</sub>	$V_{DD}$ =-4V, $V_{GEN}$ =-4.5V, $R_{L}$ =1.2 $\Omega$ ,		35	53	no	
Turn-Off Delay Time <sup>(Note 1,4)</sup>	t <sub>d(off)</sub>	$I_D$ =-3.3A, $R_G$ =1 $\Omega$		32	48	ns	
Turn-Off Fall Time <sup>(Note 1,4)</sup>	t <sub>f</sub>			10	20		
Turn-On Delay Time <sup>(Note 1,4)</sup>	t <sub>d(on)</sub>			5	10		
Turn-On Rise Time <sup>(Note 1,4)</sup>	t <sub>r</sub>	$V_{DD}$ =-4V, $V_{GEN}$ =-8V, $R_L$ =1.2 $\Omega$ ,		11	17		
Turn-Off Delay Time <sup>(Note 1,4)</sup>	t <sub>d(off)</sub>	$I_D$ =-3.3A, $R_G$ =1 $\Omega$		22	33	ns	
Turn-Off Fall Time <sup>(Note 1,4)</sup>	t <sub>f</sub>			16	24		
Drain-Source Body Diode Cha	racteristi	cs				1	
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> =25°C			-4.2	А	
Pulse Diode Forward Current <sup>(Note 3)</sup>	I <sub>SM</sub>				-10		
Body Diode Voltage	V <sub>SD</sub>	I <sub>F</sub> =-3.3A		-0.8	-1.2	V	

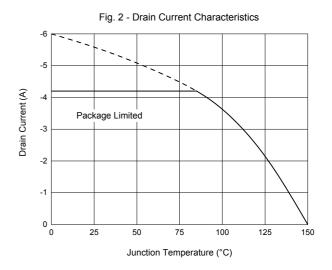
### Note:

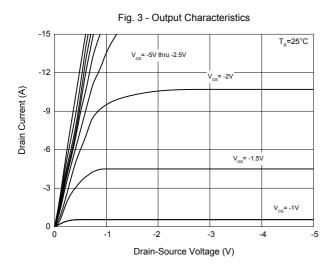
- 1. Guaranteed by Design, Not Subject to Production Testing.
- 2. Repetitive Rating: Pulse Width Limited by Max. Junction Temperature.
- 3. Pulse Test: Pulse Width≤300µs,Duty Cycle≤2%.
- 4. These Parameters Have No Way to Verify.

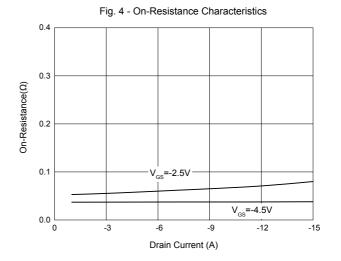


### **Curve Characteristics**











## **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

Note: Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

#### \*\*\*IMPORTANT NOTICE\*\*\*

**Micro Commercial Components Corp.** reserves the right to make changes without further notice to any product herein to make corrections, ons, enhancements, improvements, or other changes. **Micro Commercial Components Corp**. does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp**, and all the companies whose products are represented on our website, harmless against all damages.

#### \*\*\*LIFE SUPPORT\*\*\*

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

#### \*\*\*CUSTOMER AWARENESS\*\*\*

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.